

GENERAL PURPOSE AMPLIFIER

Typical Applications

- Broadband, Low Noise Gain Blocks
- IF or RF Buffer Amplifiers
- Driver Stage for Power Amplifiers
- Final PA for Low Power Applications
- Broadband Test Equipment

Product Description

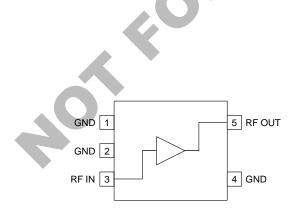
The RF2333 is a general purpose, low-cost RF amplifier IC. The device is manufactured on an advanced Gallium Arsenide Heterojunction Bipolar Transistor (HBT) process, and has been designed for use as an easily-cascadable 50Ω gain block. Applications include IF and RF amplification in wireless voice and data communication products operating in frequency bands up to $6000\,\text{MHz}.$ The device is self-contained with 50Ω input and output impedances and requires only two external DC biasing elements to operate as specified. The RF2333 is available in a very small industry-standard SOT23 5-lead surface mount package, enabling compact designs which conserve board space.

Optimum Technology Matching® Applied

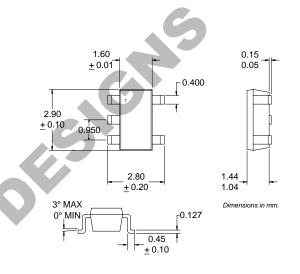
☐ Si BJT☐ Si Bi-CMOS

✓ GaAs HBT
☐ SiGe HBT

☐ GaAs MESFET☐ Si CMOS



Functional Block Diagram



Package Style: SOT 5 Lead

Features

- DC to 6000MHz Operation
- Internally matched Input and Output
- 10dB Small Signal Gain
- +34dBm Output IP3
- +18.5dBm Output Power
- Good Gain Flatness

Ordering Information

RF2333 PCBA General Purpose Amplifier
RF2333 PCBA Fully Assembled Evaluation Board

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RF2333

Absolute Maximum Ratings

Parameter	Rating	Unit			
Supply Current	120	mA			
Input RF Power	+20	dBm			
Operating Ambient Temperature	-40 to +65	°C			
Storage Temperature	-60 to +150	°C			



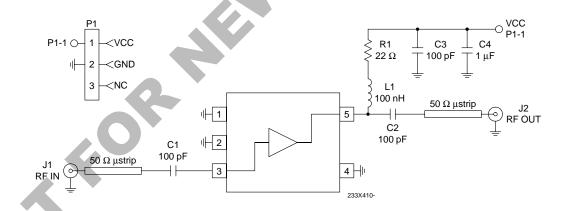
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Doromotor		Specification		l lasit	Condition	
Parameter	Min.	Тур.	Max.	Unit	Condition	
Overall					T=25°C, V _D =5.5V, I _{CC} =70mA	
Frequency Range		DC to 6000		MHz		
3dB Bandwidth		6		GHz		
Gain		11.2		dB	Freq=100MHz	
		11		dB	Freq=1000MHz	
		10.4		dB	Freq=2000MHz	
		10.2		dB ◀	Freq=3000MHz	
		10			Freq=4000MHz	
		9.2			Freq=5000MHz	
		8.3			Freq=6000MHz	
Gain Flatness		±0.4		dB	100MHz to 2000MHz	
Noise Figure		8.2		dB	Freq=2000MHz	
Input VSWR		1.7:1			In a 50Ω system, DC to 4000MHz	
Output VSWR		1.7:1			In a 50Ω system, DC to $4000 MHz$	
Output IP ₃		+34.5		dBm	Freq=1000MHz±50kHz, P _{TONE} =-10dBm	
Output P _{1dB}		+18.5		dBm	Freq=1000MHz	
Reverse Isolation		17		dB	Freq=2000MHz	
Power Supply					With 22Ω bias resistor	
Device Operating Voltage	5.0	5.5	6.0	V	At pin 5 with I _{CC} =70mA	
Operating Current		70		mA		

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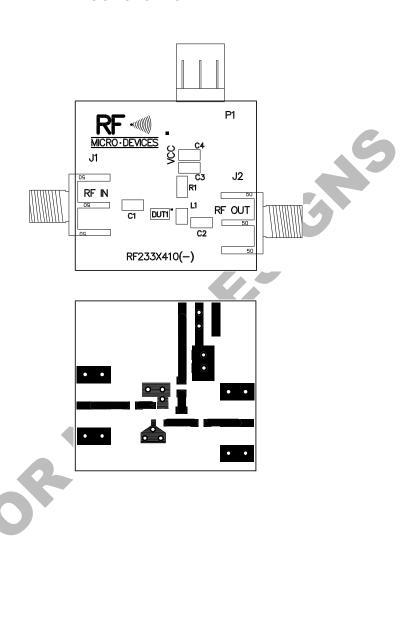
Pin	Function	Description	Interface Schematic
1	GND	Ground connection. Keep traces physically short and connect immediately to ground plane for best performance.	
2	GND	Same as pin 1.	
3	RF IN	RF input pin. This pin is NOT internally DC blocked. A DC blocking capacitor, suitable for the frequency of operation, should be used in most applications. DC coupling of the input is not allowed, because this will override the internal feedback loop and cause temperature instability.	
4	GND	Same as pin 1.	
5	RF OUT	RF output and bias pin. Biasing is accomplished with an external series resistor and choke inductor to V_{CC} . The resistor is selected to set the DC current into this pin to a desired level. The resistor value is determined by the following equation: $R = \frac{(V_{SUPPLY} - V_{DEVICE})}{I_{CC}}$ Care should also be taken in the resistor selection to ensure that the current into the part never exceeds 120 mA over the planned operating temperature . This means that a resistor between the supply and this pin is always required, even if a supply near 5.5V is available, to provide DC feedback to prevent thermal runaway. Because DC is present on this pin, a DC blocking capacitor, suitable for the frequency of operation, should be used in most applications. The supply side of the bias network should also be well bypassed.	RF IN O

Evaluation Board Schematic

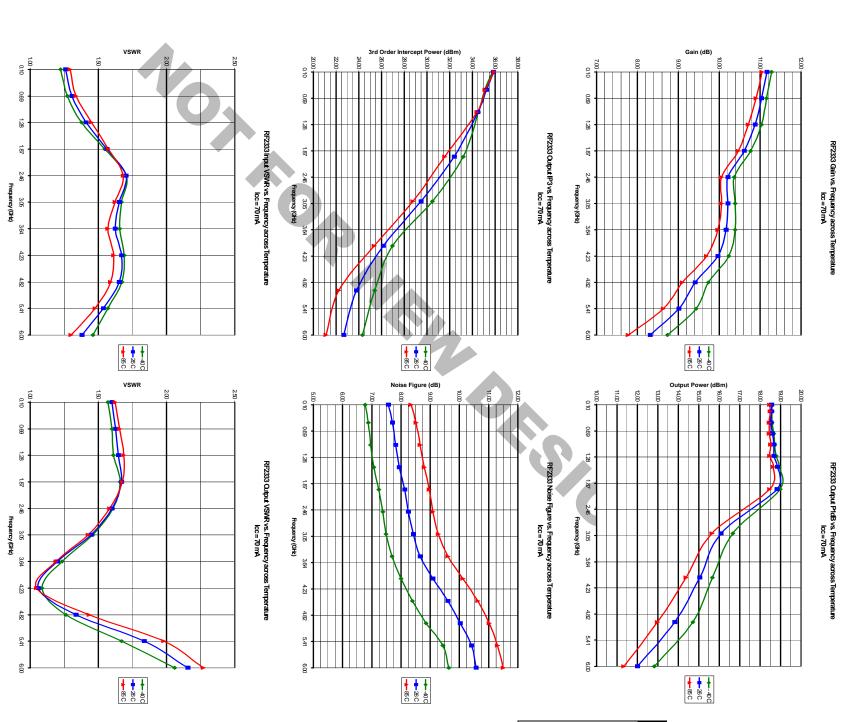


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Evaluation Board Layout Board Size 1" x 1"



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